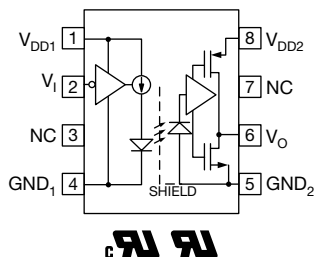
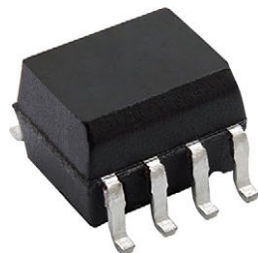


## High Speed Optocoupler, 25 MBd, SOIC-8 Package



### FEATURES

- CMOS logic digital input and output
- High speed data rate of 25 MBd
- Wide supply voltage range 2.7 V to 5.5 V
- Material categorization:  
for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### DESCRIPTION

The VOIH72A is a single channel 25 MBd high speed optocoupler in CMOS technology. Utilizing an input LED driver with a high speed IRED coupled with an integrated optical detector IC. A true digital input and output interface, in combination with the very low pulse width distortion of max. 6 ns and a high noise immunity of minimum 20 kV/ $\mu$ s enable an easy integration into digital logic systems.

### APPLICATIONS

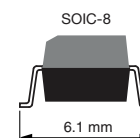
- Galvanic isolation in digital systems
- Ground loop elimination
- Digital bus system isolation
- PLC and ATE interface isolation
- Feedback control in digital power supplies

### AGENCY APPROVALS

- UL 1577 (pending)
- cUL 1577 (pending)

### ORDERING INFORMATION

|             |   |   |   |   |   |   |                |   |   |   |               |   |
|-------------|---|---|---|---|---|---|----------------|---|---|---|---------------|---|
| V           | O | I | H | 7 | 2 | A | -              | X | 0 | 0 | 1             | T |
| PART NUMBER |   |   |   |   |   |   | PACKAGE OPTION |   |   |   | TAPE AND REEL |   |



#### AGENCY CERTIFIED / PACKAGE

**UL, cUL**

SOIC-8

VOIH72AT

#### Note

- Additional options may be possible, please contact sales office

### TRUTH TABLE (positive logic)

| INPUT | OUTPUT |
|-------|--------|
| H     | H      |
| L     | L      |

**ABSOLUTE MAXIMUM RATINGS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| PARAMETER                 | TEST CONDITION     | SYMBOL     | VALUE                   | UNIT               |
|---------------------------|--------------------|------------|-------------------------|--------------------|
| <b>INPUT</b>              |                    |            |                         |                    |
| Supply voltage            |                    | $V_{DD1}$  | -0.5 to 6.0             | V                  |
| Input voltage             |                    | $V_I$      | -0.5 to $V_{DD1} + 0.5$ | V                  |
| Input current             |                    | $I_I$      | 15                      | mA                 |
| Input power dissipation   |                    | $P_{diss}$ | 100                     | mW                 |
| <b>OUTPUT</b>             |                    |            |                         |                    |
| Supply voltage            |                    | $V_{DD2}$  | -0.5 to 6.0             | V                  |
| Output voltage            |                    | $V_O$      | -0.5 to $V_{DD2} + 0.5$ | V                  |
| Output current            |                    | $I_O$      | 10                      | mA                 |
| Output power dissipation  |                    | $P_{diss}$ | 50                      | mW                 |
| <b>COUPLER</b>            |                    |            |                         |                    |
| Isolation test voltage    | $t = 1\text{ min}$ | $V_{ISO}$  | 3750                    | $V_{RMS}$          |
| Storage temperature       |                    | $T_{stg}$  | -55 to +150             | $^{\circ}\text{C}$ |
| Operating temperature     |                    | $T_{amb}$  | -40 to +110             | $^{\circ}\text{C}$ |
| Lead solder temperature   | for 10 s           |            | 260                     | $^{\circ}\text{C}$ |
| Solder reflow temperature | for 1 min          |            | 260                     | $^{\circ}\text{C}$ |

**Note**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

**RECOMMENDED OPERATING CONDITION**

| PARAMETER               | TEST CONDITION | SYMBOL    | MIN. | MAX.      | UNIT               |
|-------------------------|----------------|-----------|------|-----------|--------------------|
| Operating temperature   |                | $T_{amb}$ | -40  | +110      | $^{\circ}\text{C}$ |
| Input supply voltage    |                | $V_{DD1}$ | 2.7  | 5.5       | V                  |
| Output supply voltage   |                | $V_{DD2}$ | 2.7  | 5.5       | V                  |
| Logic low input voltage |                | $V_{IL}$  | 0    | 0.8       | V                  |
| Logic high input level  |                | $V_{IH}$  | 2.0  | $V_{DD1}$ | V                  |

**ELECTRICAL CHARACTERISTICS** ( $T_{amb} = -40\text{ }^{\circ}\text{C}$  to  $+110\text{ }^{\circ}\text{C}$ ,  $2.7\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$ ,  $2.7\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$ , unless otherwise specified; typical values are at  $V_{DD1} = V_{DD2} = 3.3\text{ V}$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

| PARAMETER                 | TEST CONDITION                                  | SYMBOL     | MIN.            | TYP.            | MAX. | UNIT          |
|---------------------------|-------------------------------------------------|------------|-----------------|-----------------|------|---------------|
| <b>INPUT</b>              |                                                 |            |                 |                 |      |               |
| Input current             |                                                 | $I_I$      | -10             | -               | 10   | $\mu\text{A}$ |
| High level supply current |                                                 | $I_{DD1H}$ | -               | 0.65            | 5    | mA            |
| Low level supply current  |                                                 | $I_{DD1L}$ | -               | 9               | 15   | mA            |
| <b>OUTPUT</b>             |                                                 |            |                 |                 |      |               |
| High level supply current |                                                 | $I_{DD2H}$ | -               | 1.3             | 2    | mA            |
| Low level supply current  |                                                 | $I_{DD2L}$ | -               | 1.2             | 2    | mA            |
| High level output voltage | $V_I = V_{IH}$ , $I_O = -20\text{ }\mu\text{A}$ | $V_{OH}$   | $V_{DD2} - 0.4$ | $V_{DD2}$       | -    | V             |
|                           | $V_I = V_{IH}$ , $I_O = -4\text{ mA}$           | $V_{OH}$   | $V_{DD2} - 1.4$ | $V_{DD2} - 0.4$ | -    | V             |
| Low level output voltage  | $V_I = V_{IL}$ , $I_O = 20\text{ }\mu\text{A}$  | $V_{OL}$   | -               | 0               | 0.1  | V             |
|                           | $V_I = V_{IL}$ , $I_O = 4\text{ mA}$            | $V_{OL}$   | -               | 0.16            | 0.6  | V             |

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

**SWITCHING CHARACTERISTICS** ( $T_{amb} = -40\text{ }^{\circ}\text{C}$  to  $+110\text{ }^{\circ}\text{C}$ ,  $2.7\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$ ,  $2.7\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$ , unless otherwise specified; typical values are at  $V_{DD1} = V_{DD2} = 3.3\text{ V}$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

| PARAMETER                                   | TEST CONDITION                                                    | SYMBOL    | MIN. | TYP. | MAX. | UNIT |
|---------------------------------------------|-------------------------------------------------------------------|-----------|------|------|------|------|
| Propagation delay time to high output level | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | $t_{PLH}$ | -    | 29   | 40   | ns   |
| Propagation delay time to low output level  | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | $t_{PHL}$ | -    | 24   | 40   | ns   |
| Pulse width distortion                      | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | PWD       | -    | 2    | 6    | ns   |
| Propagation delay skew                      | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | $t_{PSK}$ | -    | 5.8  | 20   | ns   |
| Output rise time (10 to 90 %)               | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | $t_r$     | -    | 3.3  | -    | ns   |
| Output fall time (90 to 10 %)               | $C_L = 15\text{ pF}$ , $V_{IL} = 0\text{ V}$ , $V_{IH} = V_{DD1}$ | $t_f$     | -    | 3.1  | -    | ns   |

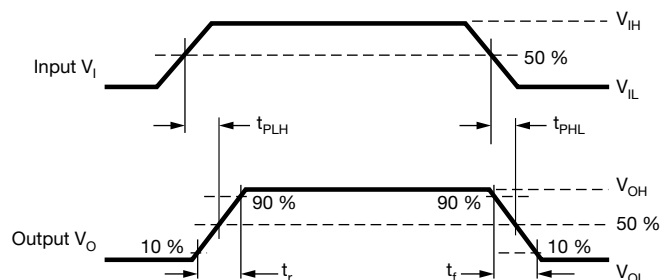
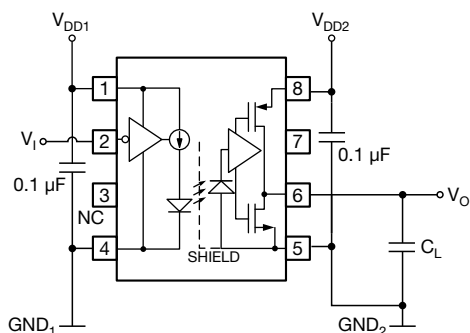


Fig. 1 - Test Circuit for  $t_{PLH}$ ,  $t_{PHL}$ ,  $t_r$  and  $t_f$

**COMMON MODE TRANSIENT IMMUNITY** ( $T_{amb} = -40\text{ }^{\circ}\text{C}$  to  $+110\text{ }^{\circ}\text{C}$ ,  $2.7\text{ V} \leq V_{DD1} \leq 5.5\text{ V}$ ,  $2.7\text{ V} \leq V_{DD2} \leq 5.5\text{ V}$ , unless otherwise specified; typical values are at  $V_{DD1} = V_{DD2} = 3.3\text{ V}$ ,  $T_{amb} = 25\text{ }^{\circ}\text{C}$ )

| PARAMETER                             | TEST CONDITION                                                          | SYMBOL   | MIN.   | TYP.   | MAX. | UNIT |
|---------------------------------------|-------------------------------------------------------------------------|----------|--------|--------|------|------|
| Common mode transient immunity (high) | $V_{CM} = 1000\text{ V}$ , $V_I = V_{DD1}$ , $V_O > 0.8 \times V_{DD2}$ | $ CM_H $ | 20 000 | 50 000 | -    | V/μs |
| Common mode transient immunity (low)  | $V_{CM} = 1000\text{ V}$ , $V_I = 0\text{ V}$ , $V_O < 0.8\text{ V}$    | $ CM_L $ | 20 000 | 30 000 | -    | V/μs |

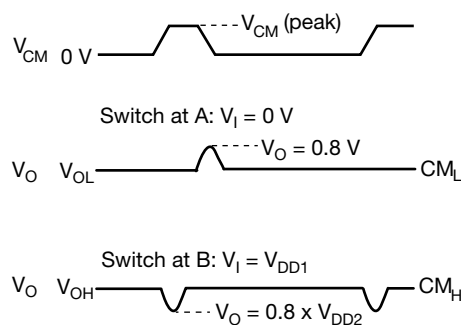
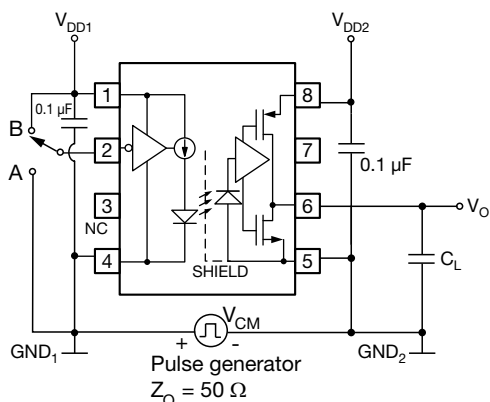


Fig. 2 - Test Circuit for Common Mode Transient Immunity

| SAFETY AND INSULATION RATINGS                |                                                                                                                      |            |                |                    |
|----------------------------------------------|----------------------------------------------------------------------------------------------------------------------|------------|----------------|--------------------|
| PARAMETER                                    | TEST CONDITION                                                                                                       | SYMBOL     | VALUE          | UNIT               |
| Climatic classification                      | According to IEC 68 part 1                                                                                           |            | 40 / 110 / 21  |                    |
| Pollution degree                             | According to DIN VDE 0109                                                                                            |            | 2              |                    |
| Comparative tracking index                   | Insulation group IIIa                                                                                                | CTI        | 175            |                    |
| Maximum rated withstanding isolation voltage | According to UL 1577, t = 1 min                                                                                      | $V_{ISO}$  | 3750           | VRMS               |
| Maximum transient isolation voltage          | according to DIN EN 60747-5-5                                                                                        | $V_{IOTM}$ | 6000           | $V_{peak}$         |
| Maximum repetitive peak isolation voltage    | according to DIN EN 60747-5-5                                                                                        | $V_{IORM}$ | 560            | $V_{peak}$         |
| Isolation resistance                         | $T_{amb} = 25\text{ }^{\circ}\text{C}$ , $V_{IO} = 500\text{ V}$                                                     | $R_{IO}$   | $\geq 10^{12}$ | $\Omega$           |
|                                              | $T_{amb} = 110\text{ }^{\circ}\text{C}$ , $V_{IO} = 500\text{ V}$                                                    | $R_{IO}$   | $\geq 10^{11}$ | $\Omega$           |
|                                              | $T_{amb} = 165\text{ }^{\circ}\text{C}$ , $V_{IO} = 500\text{ V}$                                                    | $R_{IO}$   | $\geq 10^9$    | $\Omega$           |
| Output safety power                          |                                                                                                                      | $P_{SO}$   | 350            | mW                 |
| Input safety current                         |                                                                                                                      | $I_{SI}$   | 150            | mA                 |
| Input safety temperature                     |                                                                                                                      | $T_S$      | 165            | $^{\circ}\text{C}$ |
| Creepage distance                            |                                                                                                                      |            | $\geq 4$       | mm                 |
| Clearance distance                           |                                                                                                                      |            | $\geq 4$       | mm                 |
| Insulation thickness                         |                                                                                                                      | DTI        | $\geq 0.2$     | mm                 |
| Input to output test voltage, method B       | $V_{IORM} \times 1.875 = V_{PR}$ , 100 % production test with $t_M = 1\text{ s}$ , partial discharge $< 5\text{ pC}$ | $V_{PR}$   | 1050           | $V_{peak}$         |
| Input to output test voltage, method A       | $V_{IORM} \times 1.6 = V_{PR}$ , 100 % sample test with $t_M = 10\text{ s}$ , partial discharge $< 5\text{ pC}$      | $V_{PR}$   | 896            | $V_{peak}$         |

**Note**

- As per IEC 60747-5-5, 7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of productive circuits.

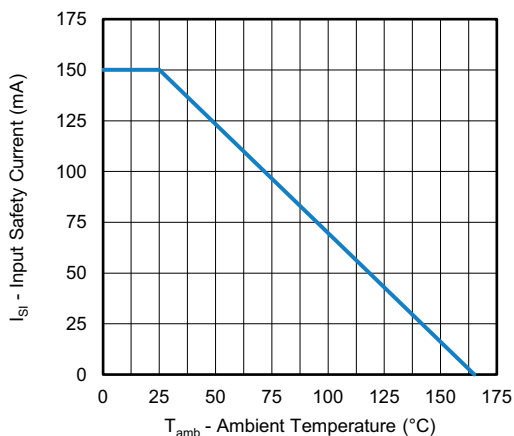


Fig. 3 - Input Safety Current vs. Ambient Temperature

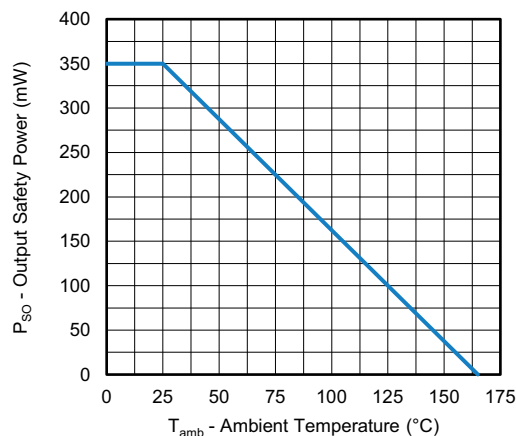


Fig. 4 - Output Safety Power vs. Ambient Temperature

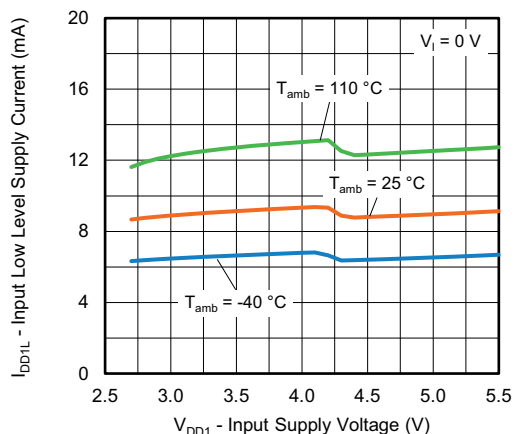
**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 5 - Input Low Level Supply Current vs. Input Supply Voltage

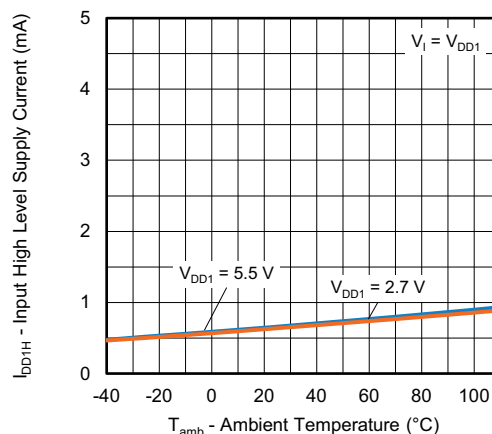


Fig. 8 - Input High Level Supply Current vs. Ambient Temperature

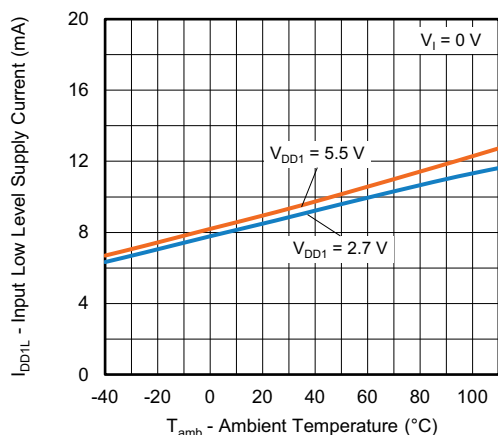


Fig. 6 - Input Low Level Supply Current vs. Ambient Temperature

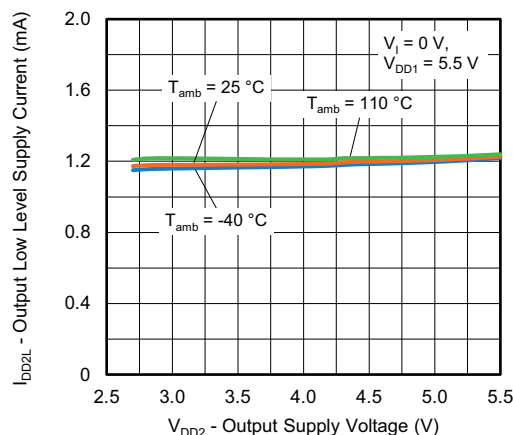


Fig. 9 - Output Low Level Supply Current vs. Output Supply Voltage

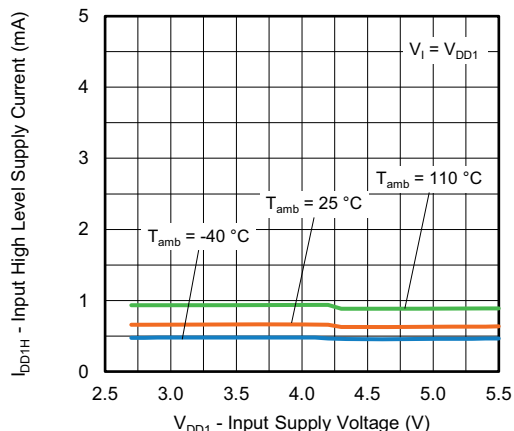


Fig. 7 - Input High Level Supply Current vs. Input Supply Voltage

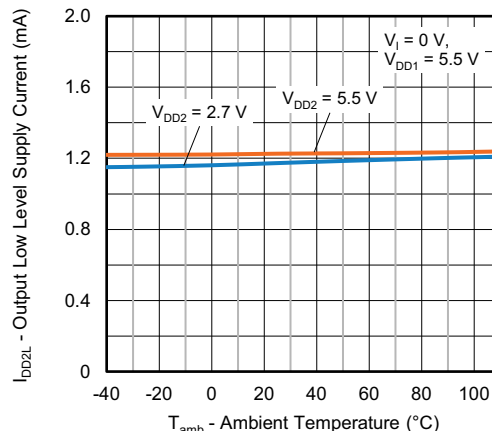


Fig. 10 - Output Low Level Supply Current vs. Ambient Temperature

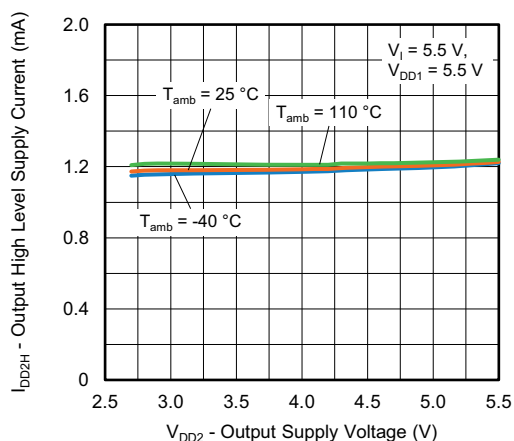


Fig. 11 - Output High Level Supply Current vs. Output Supply Voltage

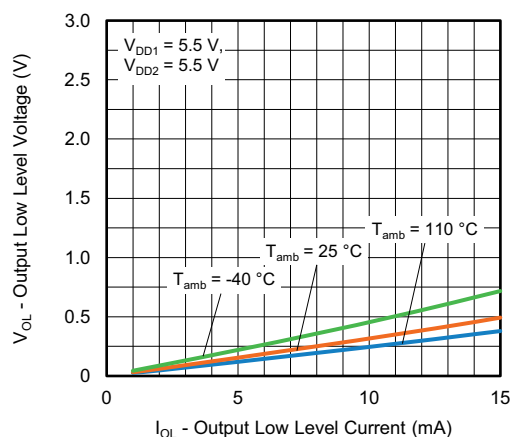


Fig. 14 - Output Low Level Voltage vs. Output Low Level Current

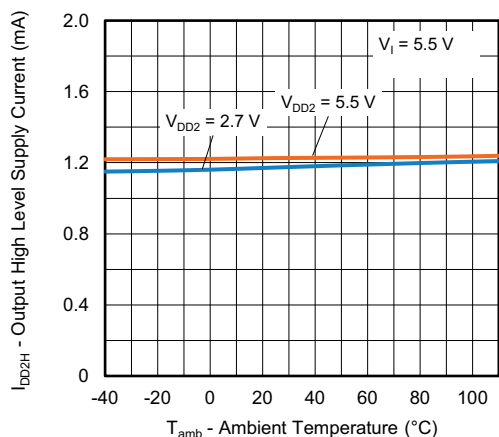


Fig. 12 - Output High Level Supply Current vs. Ambient Temperature

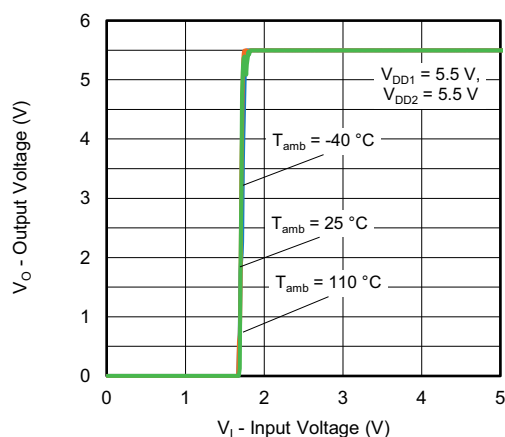


Fig. 15 - Output Voltage vs. Input Voltage

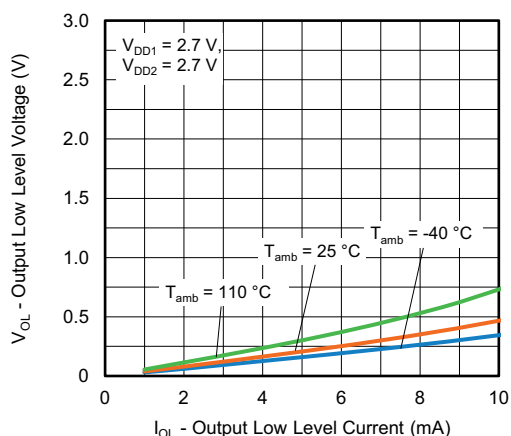


Fig. 13 - Output Low Level Voltage vs. Output Low Level Current

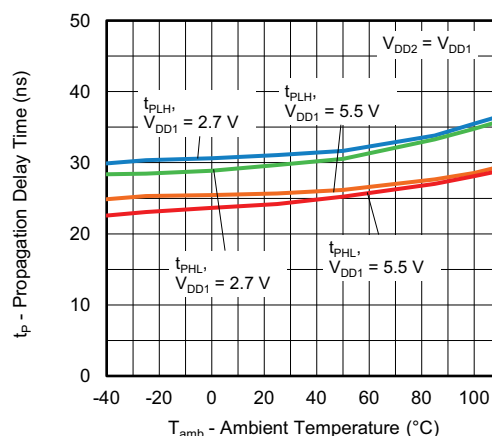


Fig. 16 - Propagation Delay Time vs. Ambient Temperature

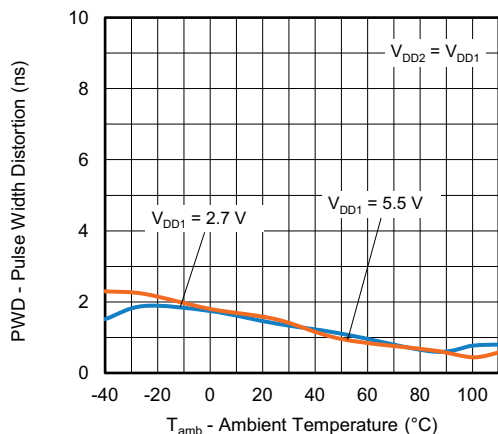


Fig. 17 - Pulse Width Distortion vs. Ambient Temperature

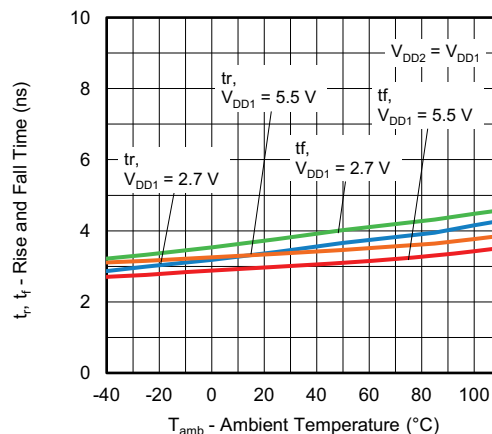
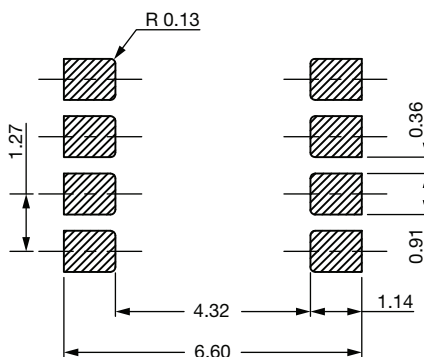
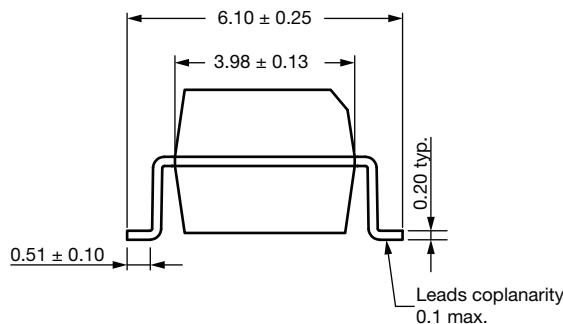
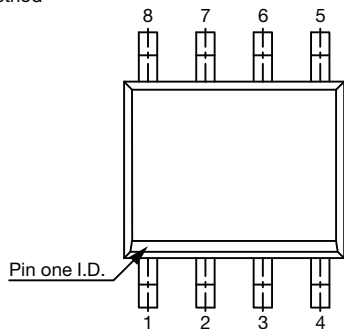
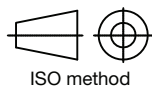
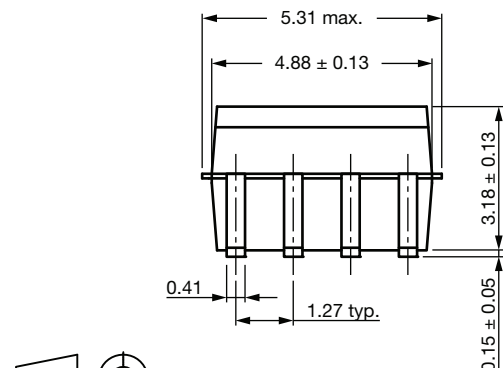


Fig. 18 - Rise and Fall Time vs. Ambient Temperature

### PACKAGE DIMENSIONS (in millimeters)



### PACKAGE MARKING

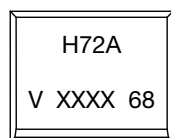


Fig. 19 - Example of VOIH72AT

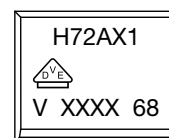


Fig. 20 - Example of VOIH72A-X001T

### Notes

- XXXX = LMC (lot marking code)
- The VDE logo is only marked on option1 (-X001) parts
- Tape and reel suffix (T) is not part of the package marking

### PACKING INFORMATION (in millimeters)

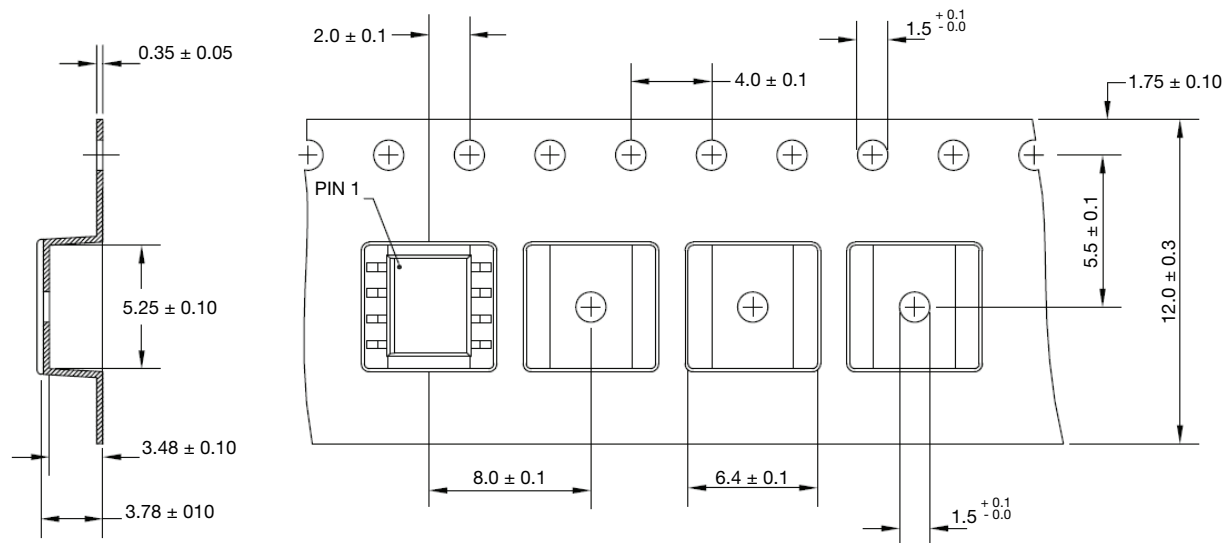


Fig. 21 - Tape and Reel Packing (2000 pieces on reel)

## SOLDER PROFILES

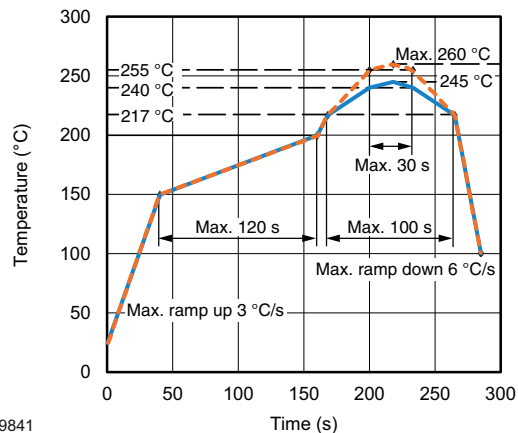


Fig. 22 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

## HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

Floor life: unlimited

Conditions:  $T_{amb} < 30\text{ }^{\circ}\text{C}$ ,  $RH < 85\%$

Moisture sensitivity level 1, according to J-STD-020

## ESD CAUTION

This is an ESD (electro static discharge) sensitive device. Electrostatic charges accumulate on the human body and test equipment and can discharge without detection. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality. ESD withstand voltage of this device is up to 1500 V according to JESD22-A114-B.





## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.